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## 3,3'-Bithiophene

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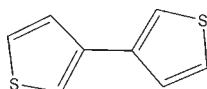
Received 10 March 2010; accepted 19 March 2010

Key indicators: single-crystal X-ray study;  $T = 150$  K; mean  $\sigma(\text{C}-\text{C}) = 0.002$  Å; disorder in main residue;  $R$  factor = 0.039;  $wR$  factor = 0.101; data-to-parameter ratio = 19.5.

The title compound,  $\text{C}_8\text{H}_6\text{S}_2$ , is disordered [occupancy ratio = 0.839 (2):0.161 (2)] and sits across a centre of symmetry. In the crystal, the molecules are linked by a weak  $\text{C}-\text{H}\cdots\pi$  interaction.

## Related literature

For a discussion of the disorder in this compound, see: Visser *et al.* (1968). For thiophene C–S bond distances, see: Allen *et al.* (1987).



## Experimental

## Crystal data

$\text{C}_8\text{H}_6\text{S}_2$   
 $M_r = 166.25$   
Orthorhombic, *Pccn*  
 $a = 7.5187$  (7) Å  
 $b = 18.2181$  (17) Å  
 $c = 5.5029$  (5) Å

$V = 753.77$  (12) Å<sup>3</sup>  
 $Z = 4$   
Mo  $K\alpha$  radiation  
 $\mu = 0.62$  mm<sup>-1</sup>  
 $T = 150$  K  
 $0.60 \times 0.40 \times 0.04$  mm

## Data collection

Bruker SMART APEXII  
diffractometer  
Absorption correction: multi-scan  
(*SADABS*; Bruker, 2004)  
 $T_{\min} = 0.709$ ,  $T_{\max} = 0.976$

11635 measured reflections  
1151 independent reflections  
987 reflections with  $I > 2\sigma(I)$   
 $R_{\text{int}} = 0.039$

## Refinement

$R[F^2 > 2\sigma(F^2)] = 0.039$   
 $wR(F^2) = 0.101$   
 $S = 1.10$   
1151 reflections  
59 parameters

6 restraints  
H-atom parameters constrained  
 $\Delta\rho_{\text{max}} = 0.48$  e Å<sup>-3</sup>  
 $\Delta\rho_{\text{min}} = -0.33$  e Å<sup>-3</sup>

Table 1

Hydrogen-bond geometry (Å, °).

$Cg$  and  $Cg'$  are the centroids of the thiophene ring in the major and minor occupancy disorder components, respectively.

$D-H\cdots A$	$D-H$	$H\cdots A$	$D\cdots A$	$D-H\cdots A$
$C2-H2\cdots Cg^i$	0.95	2.86	3.6039 (17)	136
$C2-H2\cdots Cg'^i$	0.95	2.86	3.607 (5)	136

Symmetry code: (i)  $-x + \frac{1}{2}, y, z - \frac{1}{2}$ .

Data collection: *APEX2* (Bruker, 2004); cell refinement: *SAINT* (Bruker, 2004); data reduction: *SAINT*; program(s) used to solve structure: *SHELXS97* (Sheldrick, 2008); program(s) used to refine structure: *SHELXL97* (Sheldrick, 2008); molecular graphics: *ORTEPII* (Johnson, 1976) and *PLATON* (Spek, 2009); software used to prepare material for publication: *SHELXL97*.

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Supplementary data and figures for this paper are available from the IUCr electronic archives (Reference: OM2327).

## References

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## supporting information

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## 3,3'-Bithiophene

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### S1. Comment

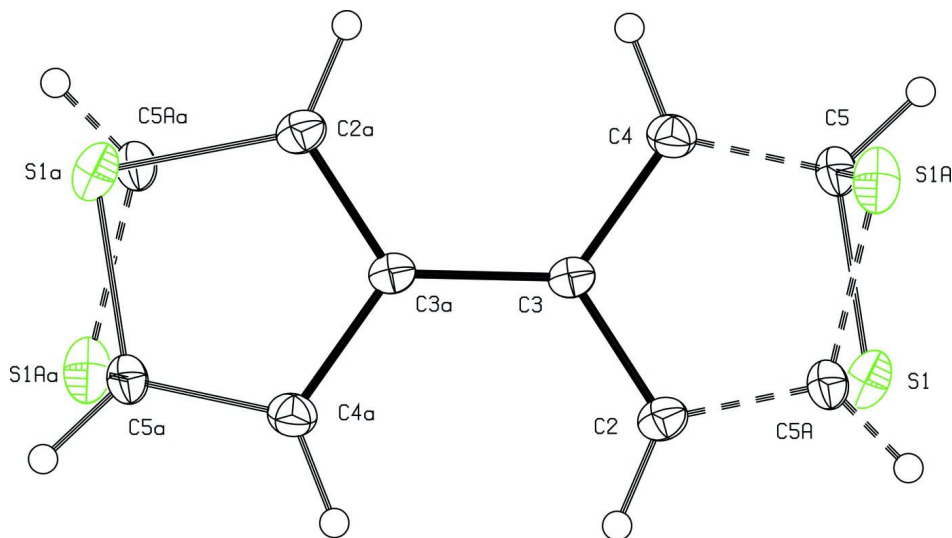
The disorder in the title compound was discussed briefly by Visser *et al.* (1968). However, this paper gives no coordinates and the structure determination was at room temperature. This is a low temperature determination. A view of the major, 0.839 (2), site occupancy, and minor, 0.161 (2), site occupancy, components are shown in Fig. 1. There is a weak C–H $\cdots\pi$  interaction, C2–H2 $\cdots$ Cg(thiophene) (0.5-x, y, z-0.5) in which H2 $\cdots$ Cg is 2.86 Å and C2 $\cdots$ Cg is 3.6039 (17) Å. The angle at H2 is 136° for the major component. The C2 $\cdots$ Cg2 distance for the minor component is 3.607 (5) Å. The H2 $\cdots$ Cg distance and angle at H2 are the same.

### S2. Experimental

The compound was obtained commercially and re-crystallised from dichloromethane.

### S3. Refinement

H atoms were treated as riding atoms with C–H(aromatic), 0.95 Å. The S atom was disordered by rotation of 180° around the bond connecting the 2 thiophene rings. The C–S distances were restrained the average value quoted in Allen, *et al.*, 1987 using tight restraints. Specifically, the C2–C5a and C4–C5 bonds were restrained in SHELXL97 refinements using DFIX 1.380 0.001 and the C5–S1, C2–S1, C4–S1A and C5A–S1A bonds were restrained using DFIX 1.72 0.001. The anisotropic thermal parameters for atom C5A (minor component) were constrained to be the same as those of atom C5 (major component) using the EADP instruction.

**Figure 1**

A view of the title compound with our numbering scheme. Displacement ellipsoids are drawn at the 30% probability level. The molecule sits across the centre-of-symmetry at (0.5,0.5,0.5). The bonds in the minor component are marked as dotted lines.

### 3,3'-bithiophene

#### Crystal data

$C_8H_6S_2$   
 $M_r = 166.25$   
 Orthorhombic, *Pccn*  
 $a = 7.5187$  (7) Å  
 $b = 18.2181$  (17) Å  
 $c = 5.5029$  (5) Å  
 $V = 753.77$  (12) Å<sup>3</sup>  
 $Z = 4$   
 $F(000) = 344$

$D_x = 1.465$  Mg m<sup>-3</sup>  
 Melting point: 406 K  
 Mo  $K\alpha$  radiation,  $\lambda = 0.71073$  Å  
 Cell parameters from 124 reflections  
 $\theta = 2.8\text{--}30.5^\circ$   
 $\mu = 0.62$  mm<sup>-1</sup>  
 $T = 150$  K  
 Plate, yellow  
 $0.60 \times 0.40 \times 0.04$  mm

#### Data collection

Bruker SMART APEXII  
 diffractometer  
 Radiation source: fine-focus sealed tube  
 Graphite monochromator  
 $\omega$  scans  
 Absorption correction: multi-scan  
 (*SADABS*; Bruker, 2004)  
 $T_{\min} = 0.709$ ,  $T_{\max} = 0.976$

11635 measured reflections  
 1151 independent reflections  
 987 reflections with  $I > 2\sigma(I)$   
 $R_{\text{int}} = 0.039$   
 $\theta_{\max} = 30.6^\circ$ ,  $\theta_{\min} = 4.3^\circ$   
 $h = -10 \rightarrow 10$   
 $k = -23 \rightarrow 26$   
 $l = -7 \rightarrow 7$

#### Refinement

Refinement on  $F^2$   
 Least-squares matrix: full  
 $R[F^2 > 2\sigma(F^2)] = 0.039$   
 $wR(F^2) = 0.101$   
 $S = 1.10$   
 1151 reflections  
 59 parameters

6 restraints  
 Primary atom site location: structure-invariant  
 direct methods  
 Secondary atom site location: difference Fourier  
 map  
 Hydrogen site location: inferred from  
 neighbouring sites

H-atom parameters constrained  
 $w = 1/[\sigma^2(F_o^2) + (0.0478P)^2 + 0.3736P]$   
 where  $P = (F_o^2 + 2F_c^2)/3$

$(\Delta/\sigma)_{\max} = 0.001$   
 $\Delta\rho_{\max} = 0.48 \text{ e } \text{Å}^{-3}$   
 $\Delta\rho_{\min} = -0.33 \text{ e } \text{Å}^{-3}$

*Special details*

**Geometry.** All esds (except the esd in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell esds are taken into account individually in the estimation of esds in distances, angles and torsion angles; correlations between esds in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell esds is used for estimating esds involving l.s. planes.

**Refinement.** Refinement of  $F^2$  against ALL reflections. The weighted  $R$ -factor  $wR$  and goodness of fit  $S$  are based on  $F^2$ , conventional  $R$ -factors  $R$  are based on  $F$ , with  $F$  set to zero for negative  $F^2$ . The threshold expression of  $F^2 > \sigma(F^2)$  is used only for calculating  $R$ -factors(gt) etc. and is not relevant to the choice of reflections for refinement.  $R$ -factors based on  $F^2$  are statistically about twice as large as those based on  $F$ , and  $R$ -factors based on ALL data will be even larger.

*Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters ( $\text{Å}^2$ )*

	<i>x</i>	<i>y</i>	<i>z</i>	$U_{\text{iso}}^*/U_{\text{eq}}$	Occ. (<1)
S1	0.44974 (10)	0.67774 (2)	0.55925 (11)	0.03155 (18)	0.839 (2)
C5A	0.446 (2)	0.6612 (2)	0.5331 (18)	0.0246 (5)	0.161 (2)
H5A	0.4003	0.7061	0.4718	0.030*	0.161 (2)
C2	0.4207 (2)	0.59508 (6)	0.4154 (2)	0.0255 (3)	
H2	0.3574	0.5891	0.2673	0.031*	
C3	0.50025 (17)	0.53842 (7)	0.5407 (2)	0.0199 (3)	
C4	0.58337 (19)	0.56308 (7)	0.7572 (3)	0.0262 (3)	
H4	0.6439	0.5314	0.8666	0.031*	
C5	0.5674 (8)	0.63775 (10)	0.7926 (7)	0.0246 (5)	0.839 (2)
H5	0.6150	0.6636	0.9277	0.030*	0.839 (2)
S1A	0.5658 (13)	0.65626 (13)	0.7988 (13)	0.0391 (12)	0.161 (2)

*Atomic displacement parameters ( $\text{Å}^2$ )*

	$U^{11}$	$U^{22}$	$U^{33}$	$U^{12}$	$U^{13}$	$U^{23}$
S1	0.0353 (3)	0.0217 (2)	0.0377 (3)	0.0028 (2)	0.0068 (2)	0.00256 (18)
C5A	0.0243 (10)	0.0215 (10)	0.0279 (10)	-0.0028 (13)	0.0000 (8)	-0.0033 (10)
C2	0.0264 (7)	0.0274 (6)	0.0227 (6)	0.0032 (5)	0.0010 (5)	0.0039 (5)
C3	0.0152 (6)	0.0247 (6)	0.0198 (6)	0.0022 (5)	0.0025 (5)	0.0022 (5)
C4	0.0234 (7)	0.0303 (7)	0.0249 (6)	0.0026 (5)	-0.0034 (5)	-0.0015 (5)
C5	0.0243 (10)	0.0215 (10)	0.0279 (10)	-0.0028 (13)	0.0000 (8)	-0.0033 (10)
S1A	0.040 (2)	0.0276 (17)	0.049 (2)	-0.001 (2)	0.0038 (15)	-0.0074 (17)

*Geometric parameters ( $\text{Å}$ ,  $^\circ$ )*

S1—C2	1.7152 (9)	C3—C4	1.4181 (19)
S1—C5	1.7215 (10)	C3—C3 <sup>i</sup>	1.470 (3)
C5A—C2	1.3802 (10)	C4—C5	1.3794 (10)
C5A—S1A	1.7203 (10)	C4—S1A	1.7180 (10)
C5A—H5A	0.9500	C4—H4	0.9500
C2—C3	1.3778 (19)	C5—H5	0.9500
C2—H2	0.9500		

C2—S1—C5	92.19 (8)	C4—C3—C3 <sup>i</sup>	123.98 (15)
C2—C5A—S1A	115.2 (3)	C5—C4—C3	113.15 (13)
C2—C5A—H5A	122.4	C3—C4—S1A	113.04 (17)
S1A—C5A—H5A	122.4	C5—C4—H4	123.4
C3—C2—C5A	111.1 (2)	C3—C4—H4	123.4
C3—C2—S1	111.81 (10)	S1A—C4—H4	123.5
C3—C2—H2	124.1	C4—C5—S1	110.87 (12)
C5A—C2—H2	124.9	C4—C5—H5	124.6
S1—C2—H2	124.1	S1—C5—H5	124.6
C2—C3—C4	111.98 (11)	C4—S1A—C5A	88.8 (2)
C2—C3—C3 <sup>i</sup>	124.05 (15)		
S1A—C5A—C2—C3	-0.2 (15)	C3 <sup>i</sup> —C3—C4—C5	179.3 (3)
C5—S1—C2—C3	-0.6 (3)	C2—C3—C4—S1A	-1.3 (5)
C5A—C2—C3—C4	1.0 (8)	C3 <sup>i</sup> —C3—C4—S1A	178.5 (4)
S1—C2—C3—C4	0.73 (16)	C3—C4—C5—S1	0.1 (5)
C5A—C2—C3—C3 <sup>i</sup>	-178.8 (8)	C2—S1—C5—C4	0.3 (4)
S1—C2—C3—C3 <sup>i</sup>	-179.03 (14)	C3—C4—S1A—C5A	1.0 (10)
C2—C3—C4—C5	-0.5 (3)	C2—C5A—S1A—C4	-0.4 (14)

Symmetry code: (i)  $-x+1, -y+1, -z+1$ .

#### Hydrogen-bond geometry ( $\text{\AA}$ , $^\circ$ )

C<sub>g</sub> and C<sub>g</sub>' are the centroids of the thiophene ring in the major and minor occupancy disorder components, respectively.

$D-H\cdots A$	$D-H$	$H\cdots A$	$D\cdots A$	$D-H\cdots A$
C2—H2 $\cdots$ C <sub>g</sub> <sup>ii</sup>	0.95	2.86	3.6039 (17)	136
C2—H2 $\cdots$ C <sub>g</sub> ' <sup>ii</sup>	0.95	2.86	3.607 (5)	136

Symmetry code: (ii)  $-x+1/2, y, z-1/2$ .